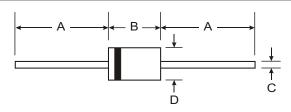


### SCHOTTKY BARRIER DIODE

## **Features**

- High Reverse Breakdown Voltage
- Low Turn-On Voltage
- Guard Ring Construction for Transient Protection



## **Mechanical Data**

Case: DO-35, Plastic

Leads: Solderable per MIL-STD-202,

Method 208

Marking: Type Number Polarity: Cathode Band

Weight: 0.13 grams (approx.)

DO-35						
Dim	Min	Max				
Α	25.40	_				
В	_	4.00				
С	_	0.60				
D	_	2.00				
All Dimensions in mm						

# **Maximum Ratings** @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	BAT46	Unit	
Peak Repetitive Reverse Voltage	$V_{RRM}$			
Working Peak Reverse Voltage	V <sub>RWM</sub> 100		V	
DC Blocking Voltage	$V_{R}$			
Forward Continuous Current (Note 1)	I <sub>FM</sub>	150	mA	
Average Rectified Output Current (Note 1)	Io	75	mA	
Repetitive Peak Forward Current (Note 1) @ t ≤ 1.0s	I <sub>FRM</sub>	350	mA	
Non-Repetitive Peak Forward Surge Current @ t = 10ms	I <sub>FSM</sub>	750	mA	
Power Dissipation (Note 1)	Pd	200	mW	
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{ heta JA}$	500	K/W	
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +125	°C	

#### **Electrical Characteristics** @ $T_A = 25$ °C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage	V <sub>(BR)R</sub>	100	_	_	V	I <sub>RS</sub> = 10μA (pulses)
Reverse Leakage Current (Note 2)	IR	_	_	0.5 5.0 0.8 7.5 2.0 15 5.0 20	μΑ	$\label{eq:controller} \begin{array}{l} V_R = 1.5V \\ V_R = 1.5V, \ T_j = 60^{\circ}C \\ V_R = 10V \\ V_R = 10V, \ T_j = 60^{\circ}C \\ V_R = 50V, \ T_j = 60^{\circ}C \\ V_R = 75V \\ V_R = 75V, \ T_j = 60^{\circ}C \\ \end{array}$
Forward Voltage Drop (Note 2)	V <sub>F</sub>	_	_	0.25 0.45 1.00	V	I <sub>F</sub> = 0.1mA I <sub>F</sub> = 10mA I <sub>F</sub> = 250mA
Junction Capacitance	Cj	_	10 6.0	_	pF	$V_R = 0V, f = 1.0MHz$ $V_R = 1.0V, f = 1.0MHz$

1. Valid provided that electrodes are kept at ambient temperature.

2.  $t < 300\mu s$ , Duty Cycle < 2%.